



N-Channel Silicon MOSFET

FW261 — General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|------------------|---|-------------|------|
| Drain-to-Source Voltage | V _{DSS} | | 30 | V |
| Gate-to-Source Voltage | V _{GSS} | | ±20 | V |
| Drain Current (DC) | I _D | | 5 | A |
| Drain Current (PW≤10s) | I _D | Duty cycle≤1% | 6 | A |
| Drain Current (PW≤100ms) | I _D | Duty cycle≤1% | 10 | A |
| Drain Current (PW≤10μs) | I _{DP} | Duty cycle≤1% | 20 | A |
| Allowable Power Dissipation | P _D | Mounted on a ceramic board (2000mm ² ×0.8mm) 1unit, PW≤10s | 1.8 | W |
| Total Dissipation | P _T | Mounted on a ceramic board (2000mm ² ×0.8mm), PW≤10s | 2.2 | W |
| Channel Temperature | T _{ch} | | 150 | °C |
| Storage Temperature | T _{stg} | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|-----------------------|--|---------|-----|-----|------|
| | | | min | typ | max | |
| Drain-to-Source Breakdown Voltage | V _{(BR)DSS} | I _D =1mA, V _{GS} =0V | 30 | | | V |
| Zero-Gate Voltage Drain Current | I _{DSS} | V _{DS} =30V, V _{GS} =0V | | | 1 | μA |
| Gate-to-Source Leakage Current | I _{GSS} | V _{GS} =±16V, V _{DS} =0V | | | ±10 | μA |
| Cutoff Voltage | V _{GSS(off)} | V _{DS} =10V, I _D =1mA | 1.2 | | 2.6 | V |
| Forward Transfer Admittance | y _{fs} | V _{DS} =10V, I _D =5A | 3.9 | 5.5 | | S |
| Static Drain-to-Source On-State Resistance | R _{DS(on)1} | I _D =5A, V _{GS} =10V | | 37 | 48 | mΩ |
| | R _{DS(on)2} | I _D =3A, V _{GS} =4V | | 64 | 83 | mΩ |
| Input Capacitance | C _{iss} | V _{DS} =10V, f=1MHz | | 460 | | pF |
| Output Capacitance | C _{oss} | V _{DS} =10V, f=1MHz | | 95 | | pF |
| Reverse Transfer Capacitance | C _{rss} | V _{DS} =10V, f=1MHz | | 75 | | pF |
| Turn-ON Delay Time | t _{d(on)} | See specified Test Circuit. | | 15 | | ns |
| Rise Time | t _r | See specified Test Circuit. | | 20 | | ns |
| Turn-OFF Delay Time | t _{d(off)} | See specified Test Circuit. | | 30 | | ns |
| Fall Time | t _f | See specified Test Circuit. | | 20 | | ns |

Marking : W261

Continued on next page.

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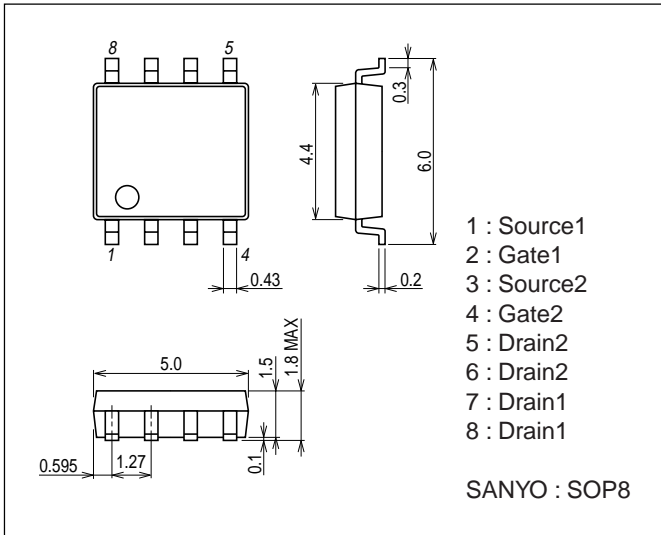
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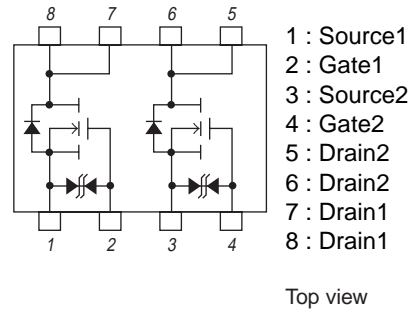
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-------------------------------|-----------------|--|---------|-----|-----|------|
| | | | min | typ | max | |
| Total Gate Charge | Qg | V _{DS} =10V, V _{GS} =10V, I _D =5A | | 8.6 | | nC |
| Gate-to-Source Charge | Qgs | V _{DS} =10V, V _{GS} =10V, I _D =5A | | 2.0 | | nC |
| Gate-to-Drain "Miller" Charge | Qgd | V _{DS} =10V, V _{GS} =10V, I _D =5A | | 1.6 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =5A, V _{GS} =0V | | 0.9 | 1.2 | V |

Package Dimensions

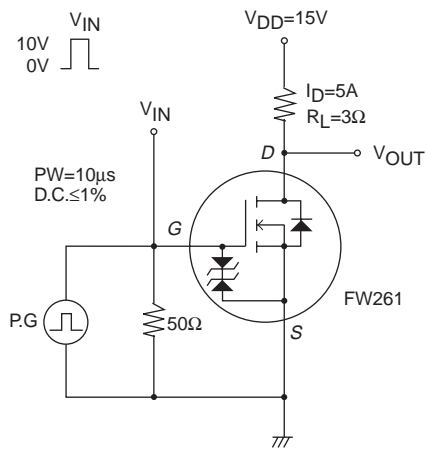
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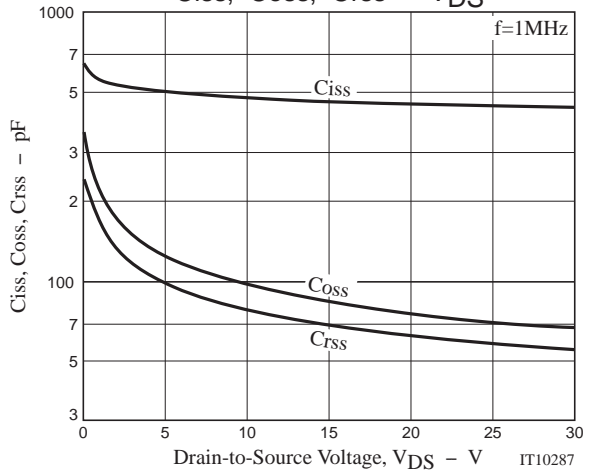
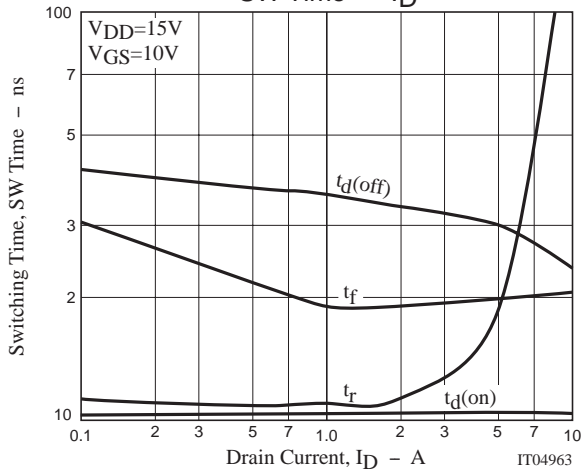
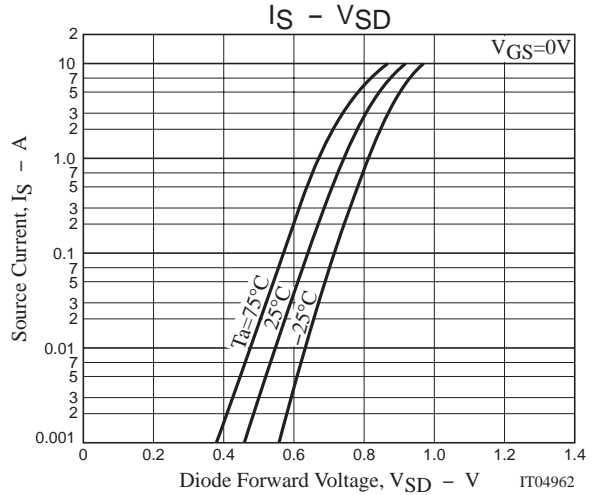
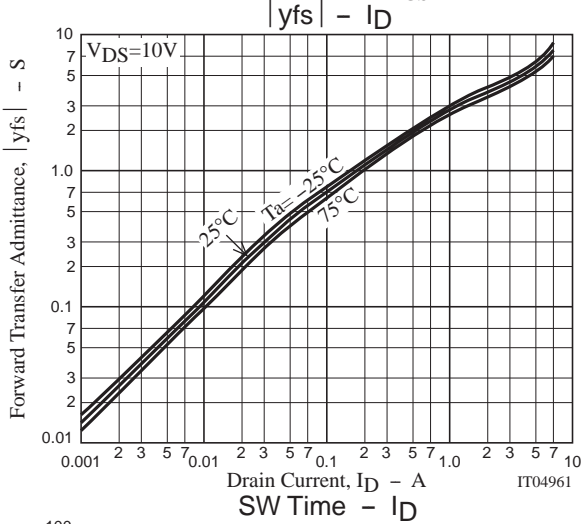
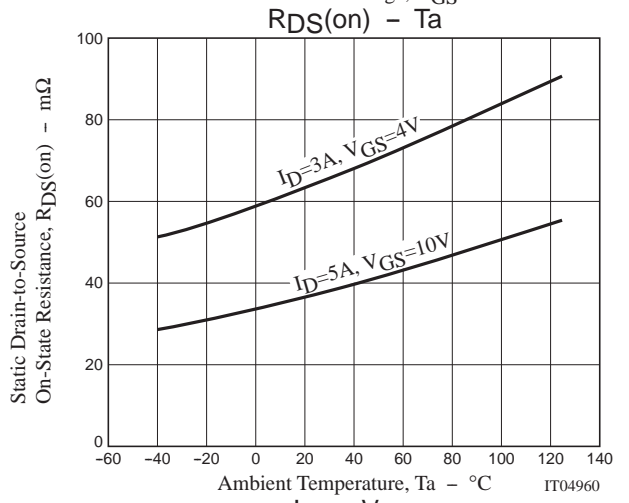
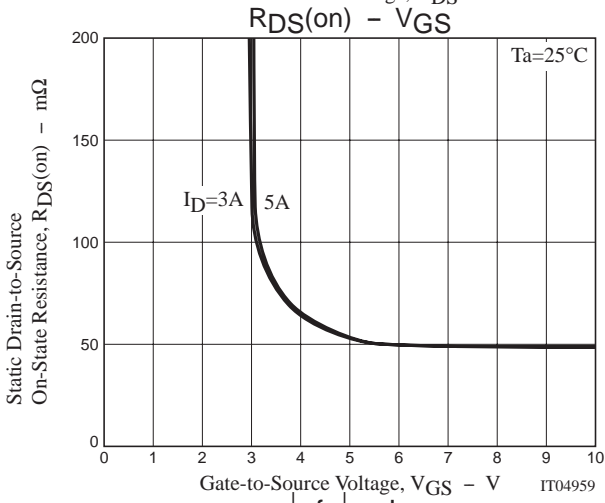
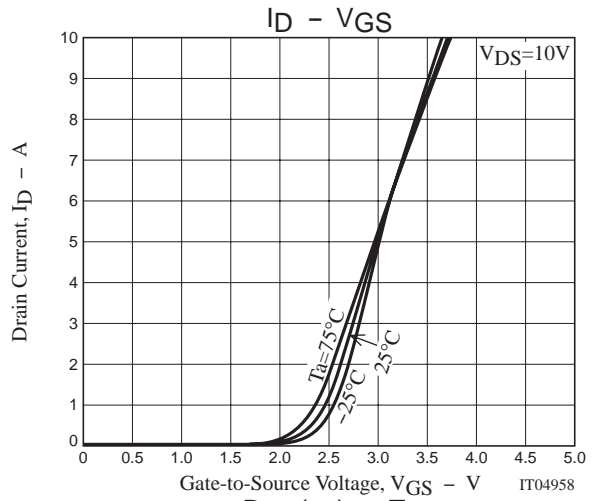
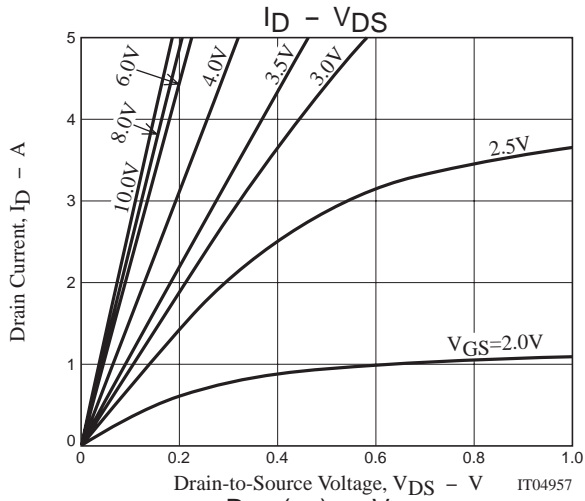


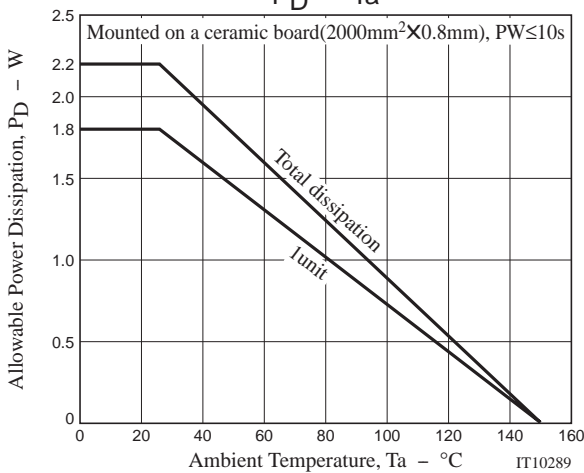
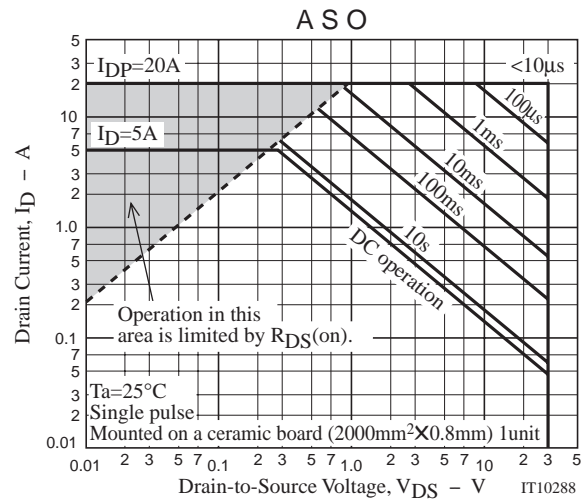
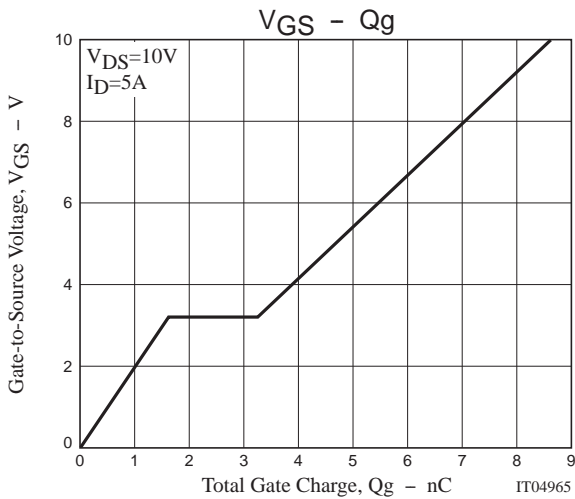
Electrical Connection



Switching Time Test Circuit







Note on usage : Since the FW261 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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